

# LINKS TO ADDITIONAL RESOURCES

30 3D Mode

PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	8.0 A					
V <sub>RRM</sub>	400 V, 600 V, 800 V, 1000 V					
I <sub>FSM</sub>	200 A					
I <sub>R</sub>	10 µA					
V <sub>F</sub> at I <sub>F</sub> = 8 A (T <sub>J</sub> = 125 °C)	0.87 V					
T <sub>J</sub> max.	150 °C					
Package	SMC (DO-214AB)					
Circuit configuration	Single					

SMC (DO-214AB)

## **FEATURES**

Surface-Mount Glass Passivated Rectifier

- Low profile package
- · Ideal for automated placement
- Glass passivated pellet chip junction
- Low forward voltage drop
- Low leakage current
- · High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

S8GS, S8JS, S8KS, S8MS

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• Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

# **TYPICAL APPLICATIONS**

For use in general purpose rectification of power supplies, inverters, converters, and freewheeling diodes for consumer, and telecommunication.

# **MECHANICAL DATA**

Case: SMC (DO-214AB) Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102 E3 suffix meets JESD 201 class 2 whisker test

Polarity: color band denotes cathode end

<b>MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	SYMBOL	S8GS	S8JS	S8KS	S8MS	UNIT	
Device marking code		S8GS	S8JS	S8KS	S8MS		
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	400	600	800	1000	V	
Maximum RMS voltage	V <sub>RMS</sub>	280	420	560	700	V	
Maximum DC blocking voltage	V <sub>DC</sub>	400	600	800	1000	V	
Manimum and a family of the day was t	I <sub>F(AV)</sub> <sup>(1)</sup>	8.0				А	
Maximum average forward rectified current	I <sub>F(AV)</sub> <sup>(2)</sup>		А				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	200				А	
Peak forward surge current single half sine-wave at 1.0 ms	I <sub>FSM</sub>	450			А		
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150				°C	

Notes

<sup>(1)</sup> Mounted on aluminum PCB 30 mm x 30 mm with aluminum heatsink

<sup>(2)</sup> Free air, mounted on recommended copper pad area







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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_J = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage	I <sub>F</sub> = 4.0 A	– T <sub>J</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.90	-	V	
	I <sub>F</sub> = 8.0 A			0.97	0.985		
	I <sub>F</sub> = 4.0 A	– T <sub>J</sub> = 125 °C		0.80	-		
	I <sub>F</sub> = 8.0 A			0.87	0.971		
Reverse current	Rated V <sub>R</sub>	T <sub>J</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	-	10		
	naleu v <sub>R</sub>	T <sub>J</sub> = 125 °C	IR (=)	-	180	μA	
Typical reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$		t <sub>rr</sub>	3.4	-	μs	
Typical junction capacitance	4.0 V, 1 MHz		CJ	63	-	pF	

#### Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width; 1 % duty cycle

<sup>(2)</sup> Pulse test: pulse width  $\leq$  40 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	S8GS	S8JS	S8KS	S8MS	UNIT
Typical thermal resistance	R <sub>0JA</sub> <sup>(1)(2)</sup>		8	8		°C/W
Typical thermal resistance	R <sub>θJM</sub> <sup>(3)</sup>	4.5				0/10

### Notes

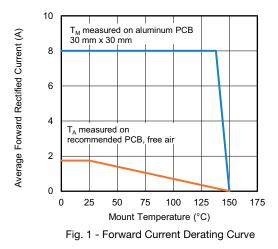
<sup>(1)</sup> The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/R_{\theta JA}$ 

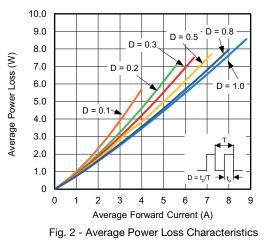
(2) Thermal resistance junction-to-ambient to follow JEDEC<sup>®</sup> 51-2A, device mounted on FR4 PCB, 2 oz., standard footprint

(3) Thermal resistance junction-to-mount to follow JEDEC® 51-14 transient dual interface test method (TDIM)

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
S8JS-E3/I	0.243	I	3500	13" diameter plastic tape and reel			

### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)







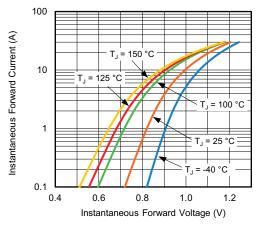


Fig. 3 - Typical Instantaneous Forward Characteristics

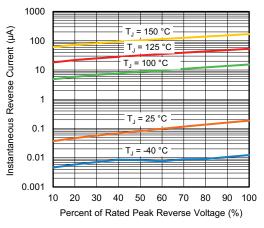
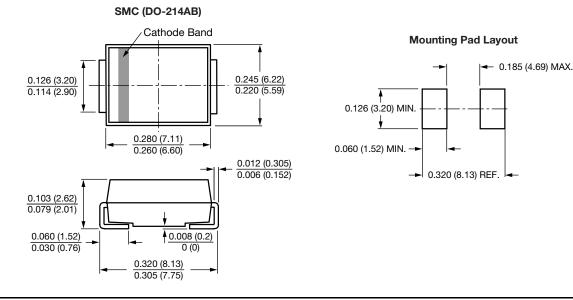


Fig. 4 - Typical Reverse Characteristics





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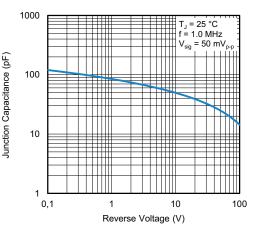


Fig. 5 - Typical Junction Capacitance

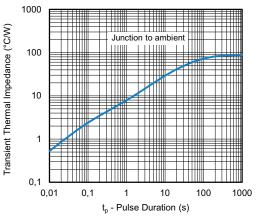


Fig. 6 - Transient Thermal Impedance

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3

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